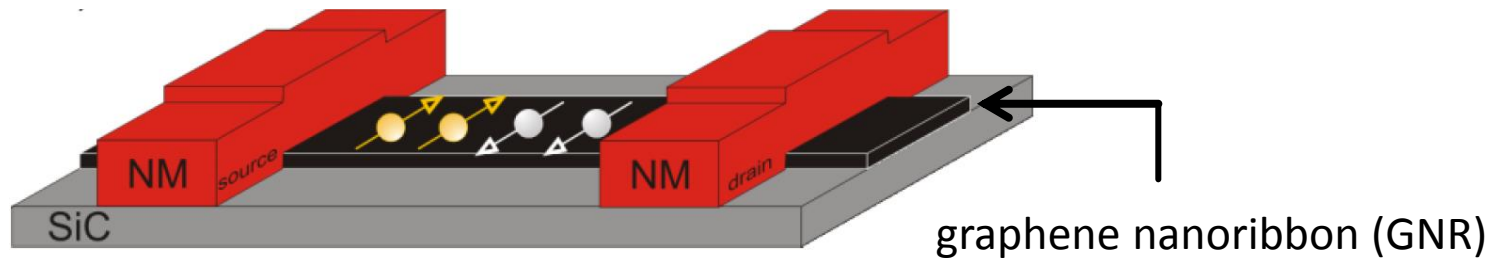


TAILSPIN

*Tailoring spin-interactions in
graphene nanoribbons for
ballistic fully spin-polarized devices*

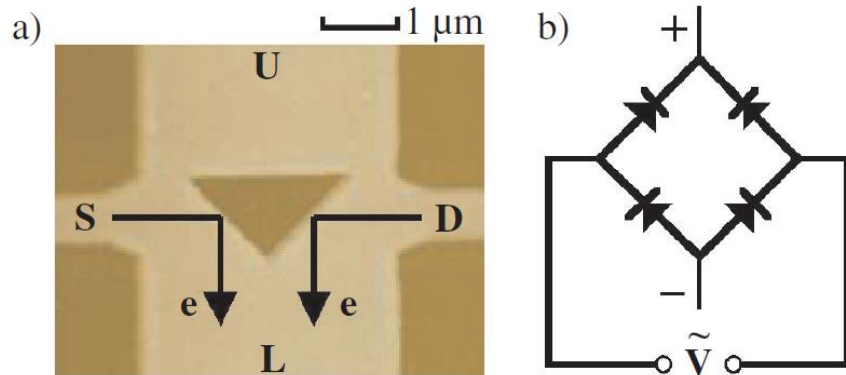


Christoph Tegenkamp, University of Hannover

The future of electronic devices

Ideal future electronic device:

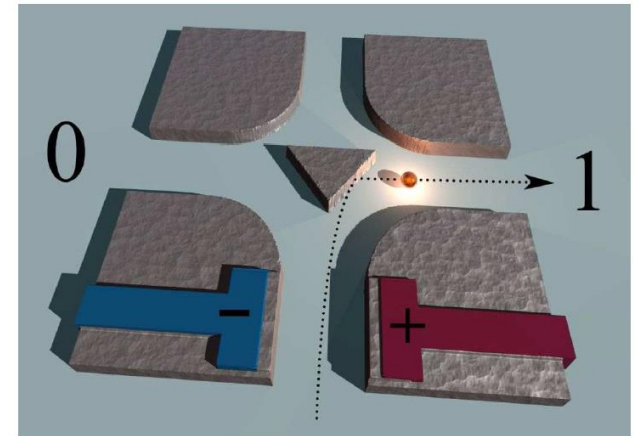
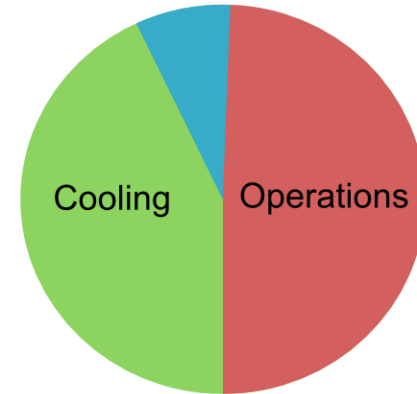
- Low heat dissipation
- High operating speed
- Large range scalability



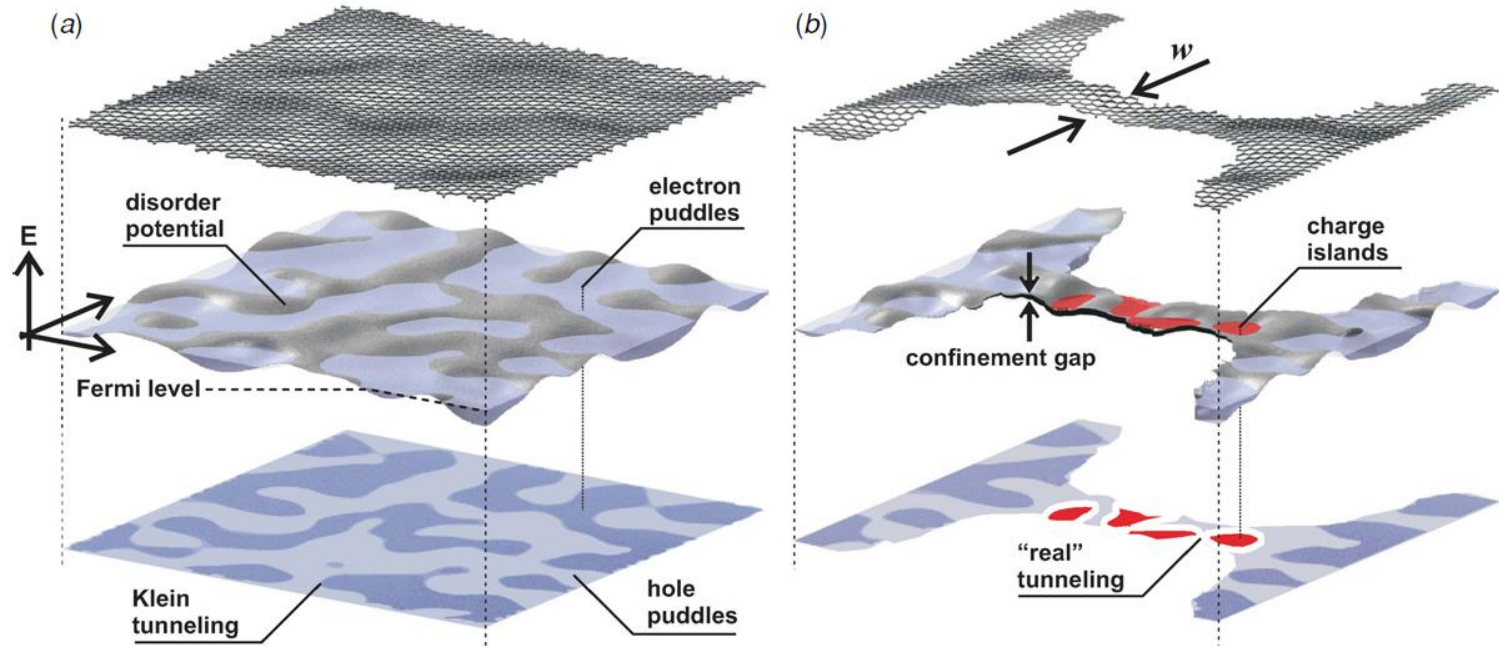
Song et al., PRL **80** (1998)

Data center energy end use

Conversion/Distribution



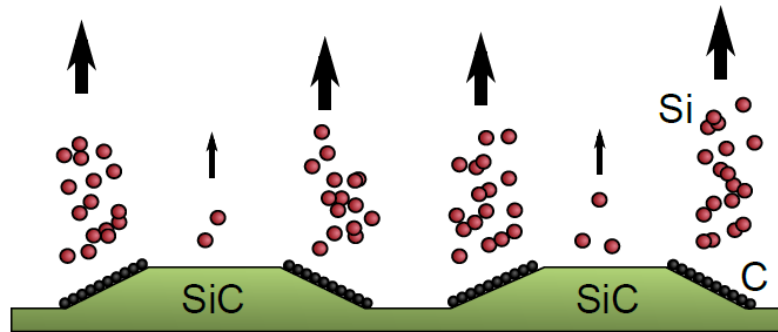
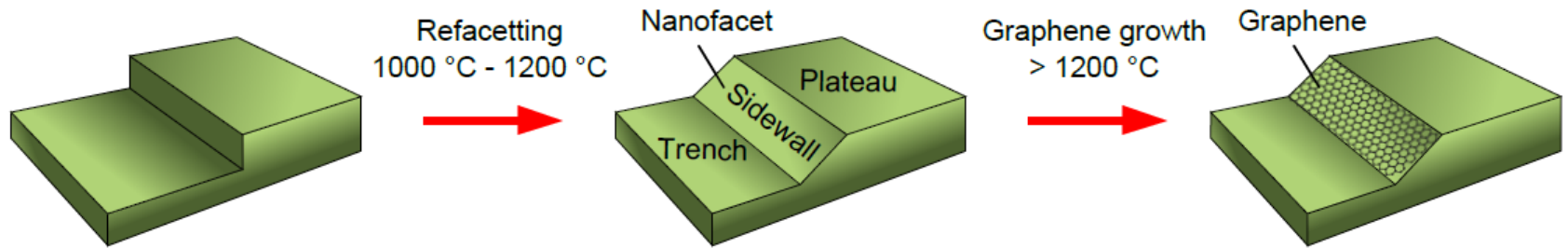
Lithographic etching of GNRs



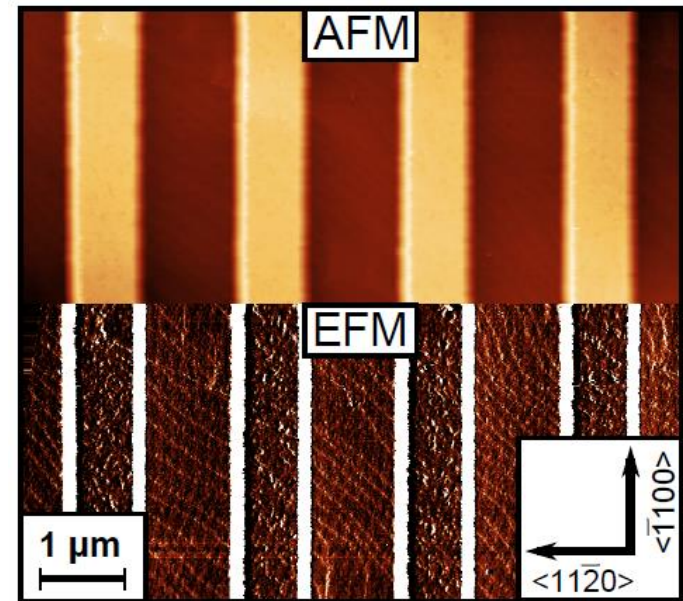
Molitor et al., SST 25 (2010)

→ Coulomb blockade

Self-assembled growth of zig-zag GNRs

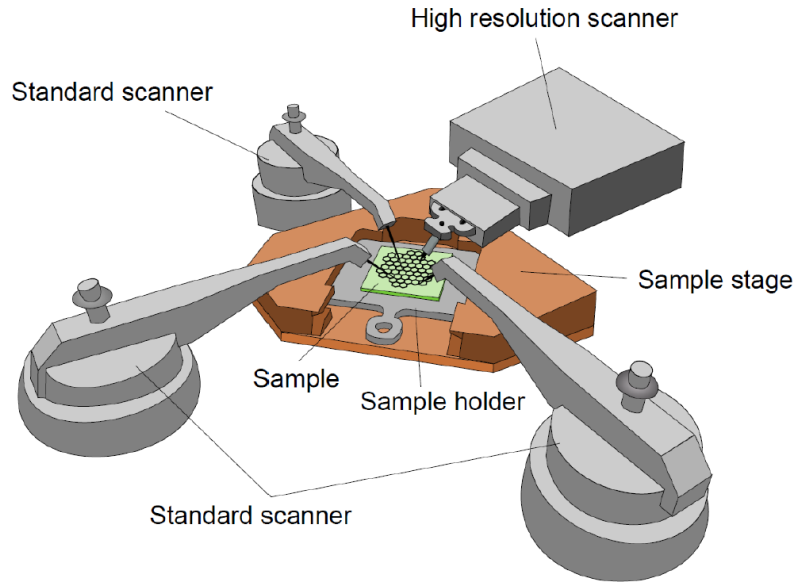


Idea: Sprinkle et al., Nature Nano. **5** (2010)

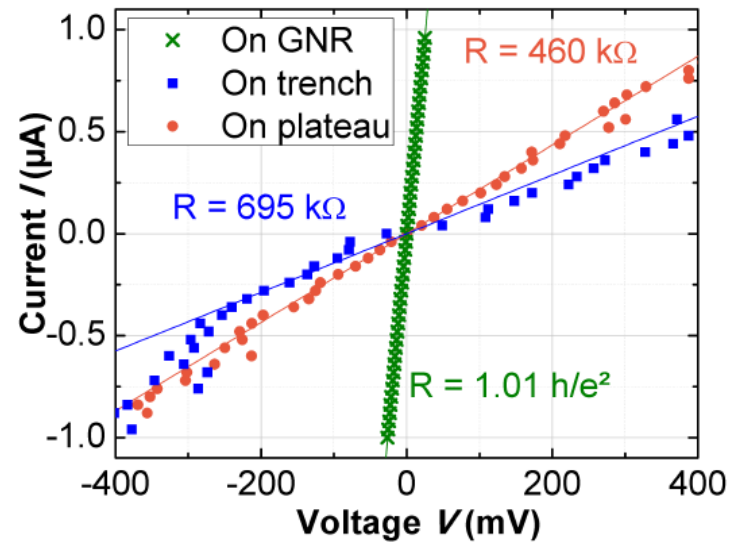
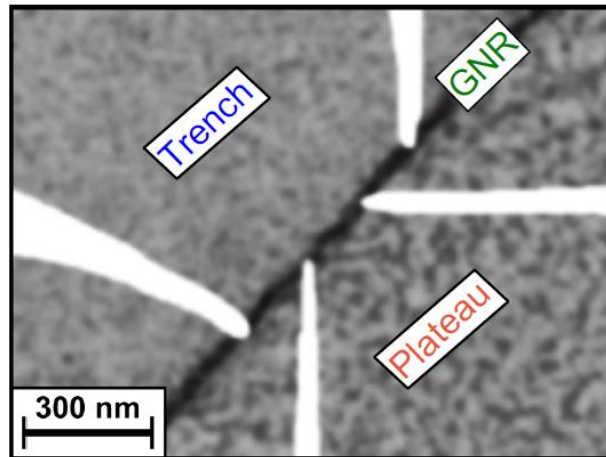


Baringhaus et al., APL **106** (2015)

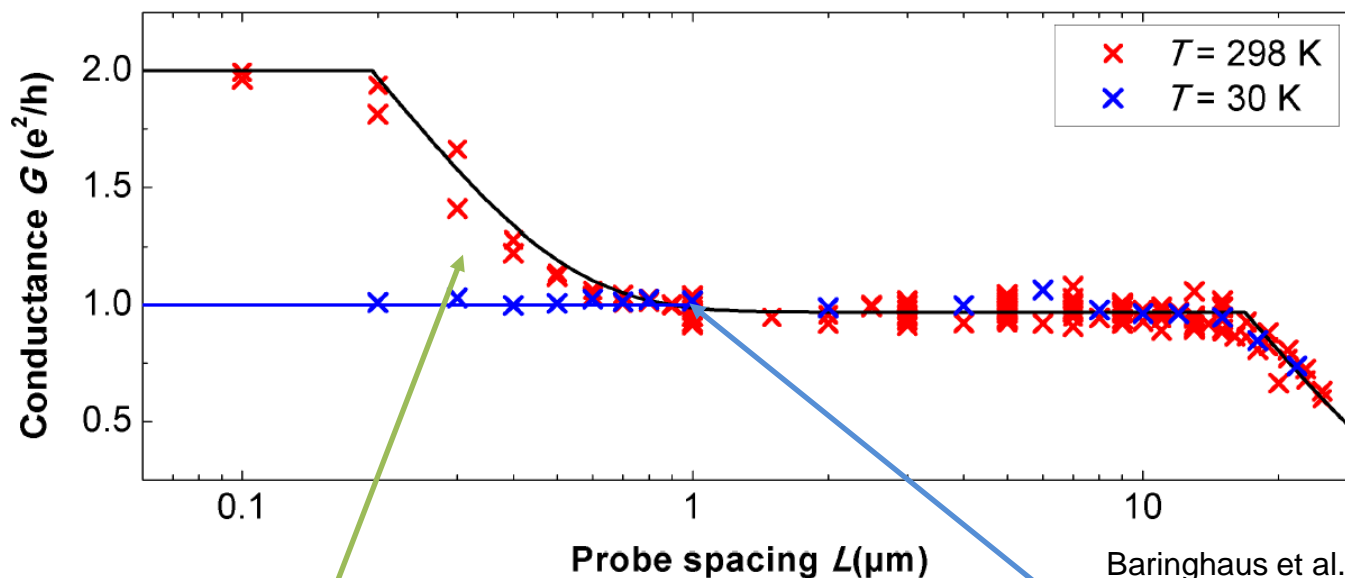
Local electronic transport



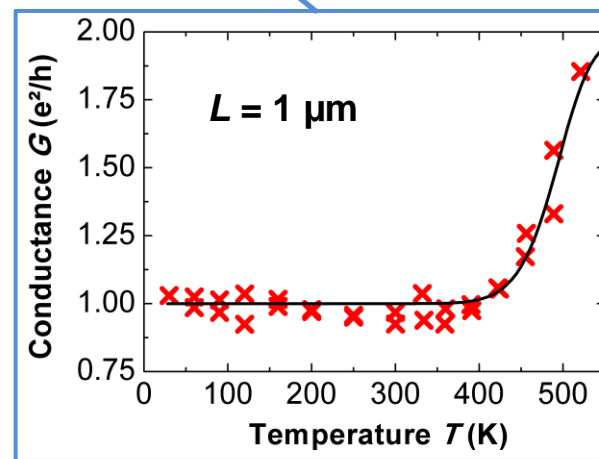
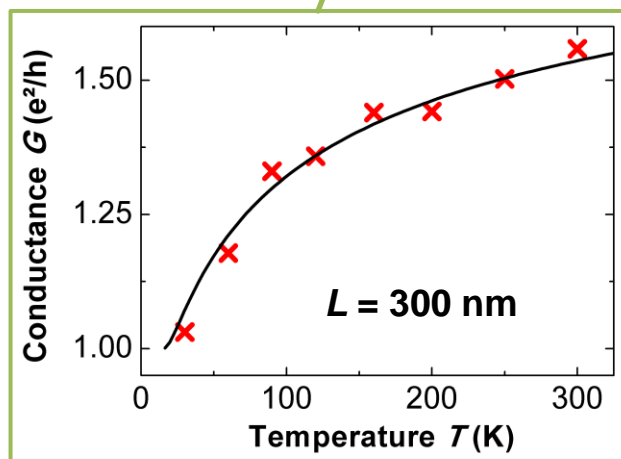
- 4 STM tips
- HR Gemini type SEM with a resolution < 4 nm
- $T_{\text{sample}} < 26$ K



Exceptional ballistic transport

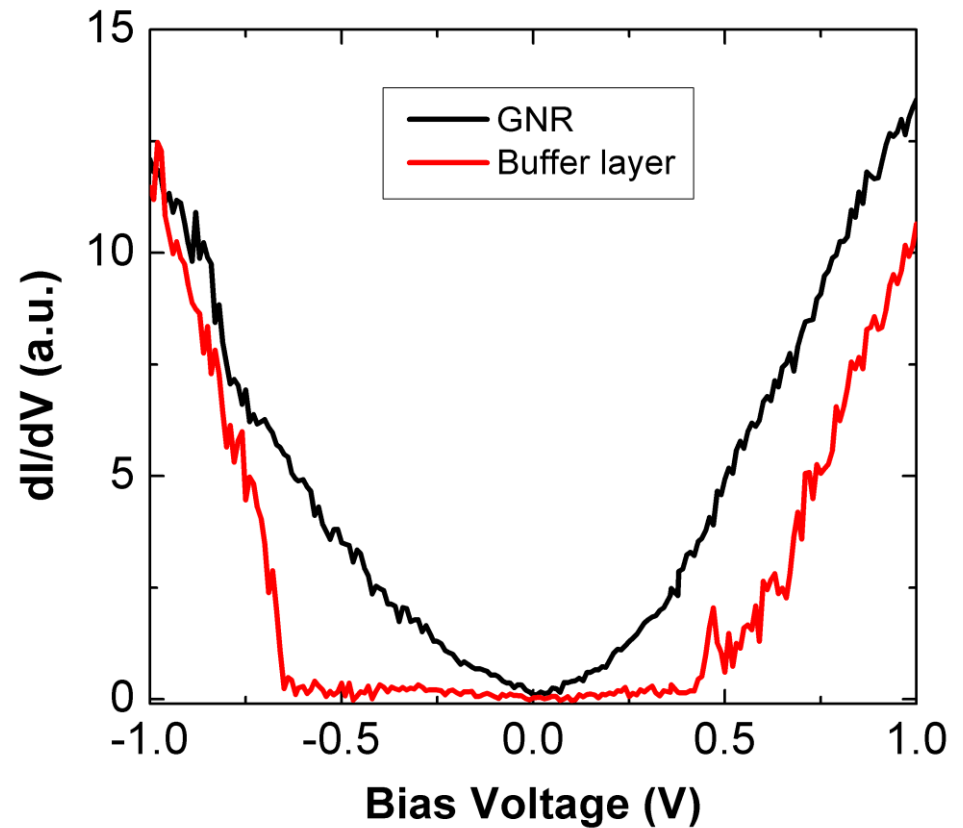
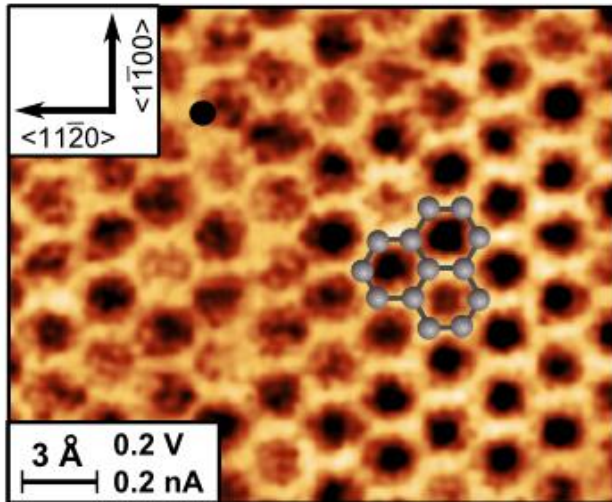
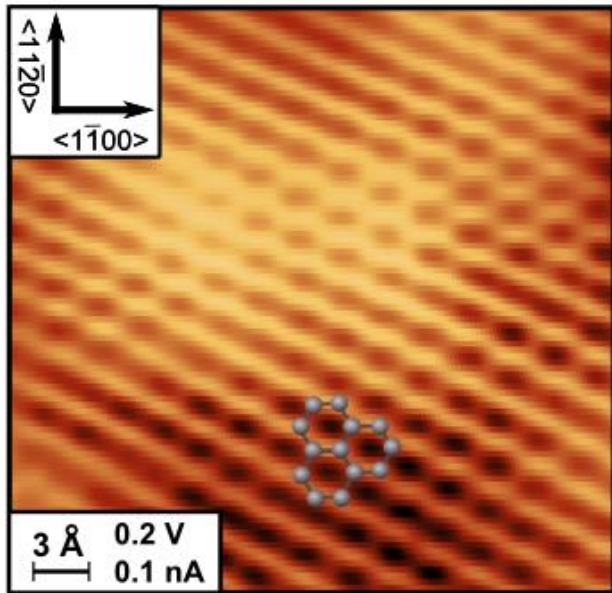


Baringhaus et al., Nature **506** (2014)



Ballistic transport through a single non-deg. channel at RT

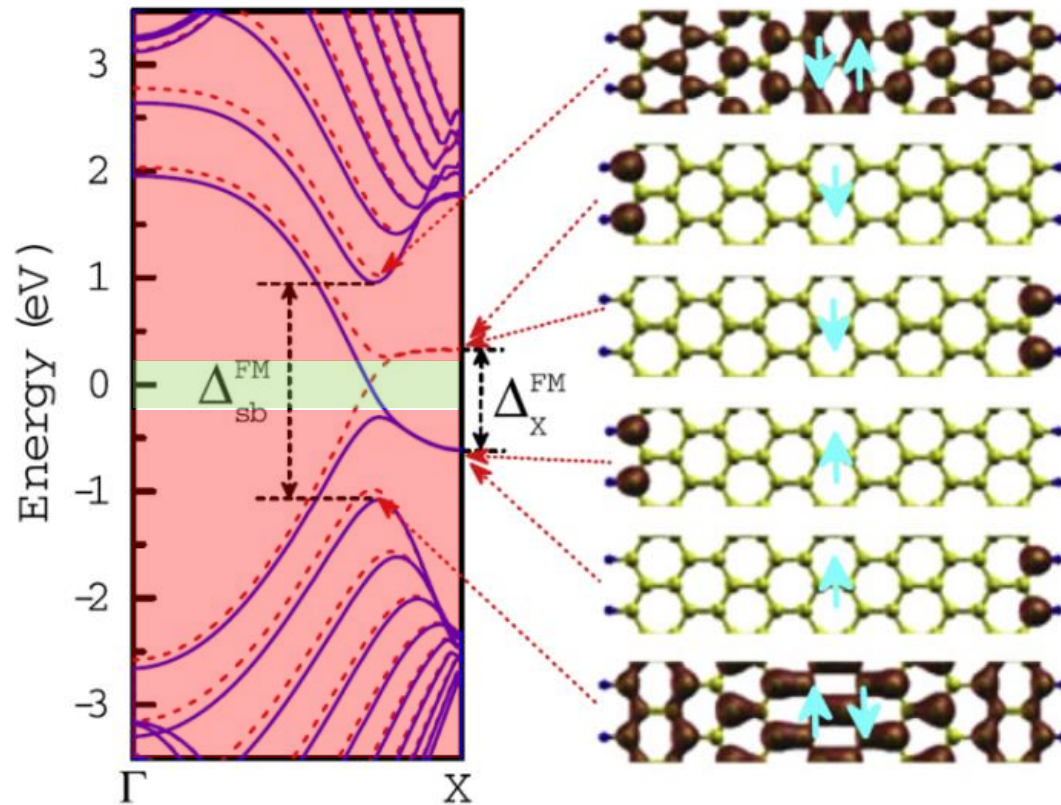
Morphology and DOS



Sidewall GNR are:

- always zigzag
- charge neutral

Perfectly conducting channel



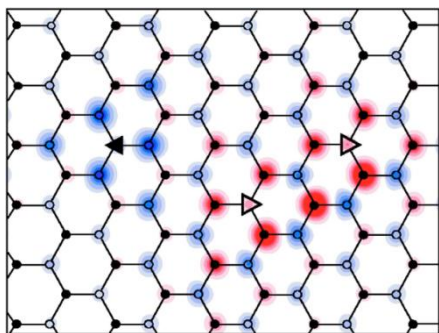
Theory: spin-polarized edge channels in zig-zag GNRs

Huang et al., J. Phys. Condens. Matter 25 (2013)

Origin of spin polarization

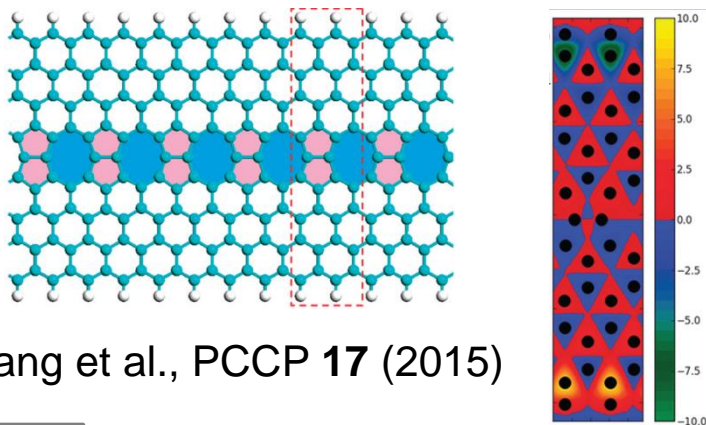
Defect induced magnetism

Adsorbates



Yazyev et al., PRB **75** (2007)

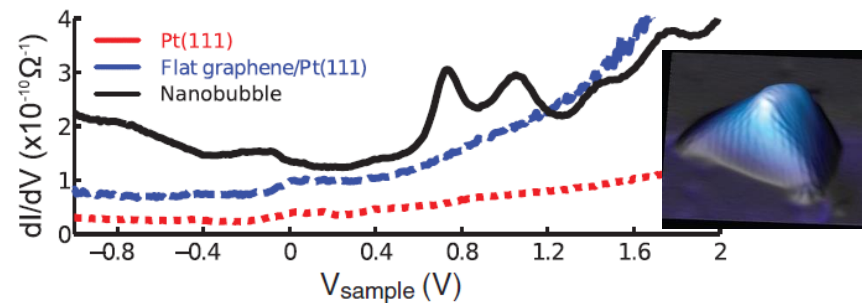
Line defects



Tang et al., PCCP **17** (2015)

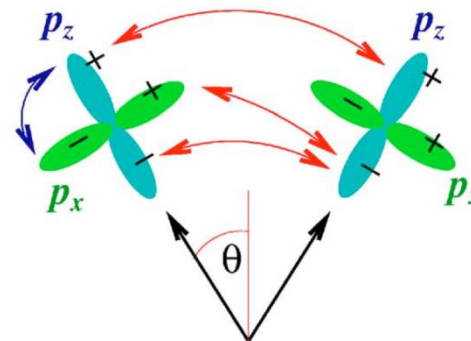
Curvature

Pseudo-magnetic fields



Levy et al., Science **329** (2010)

Spin-orbit coupling

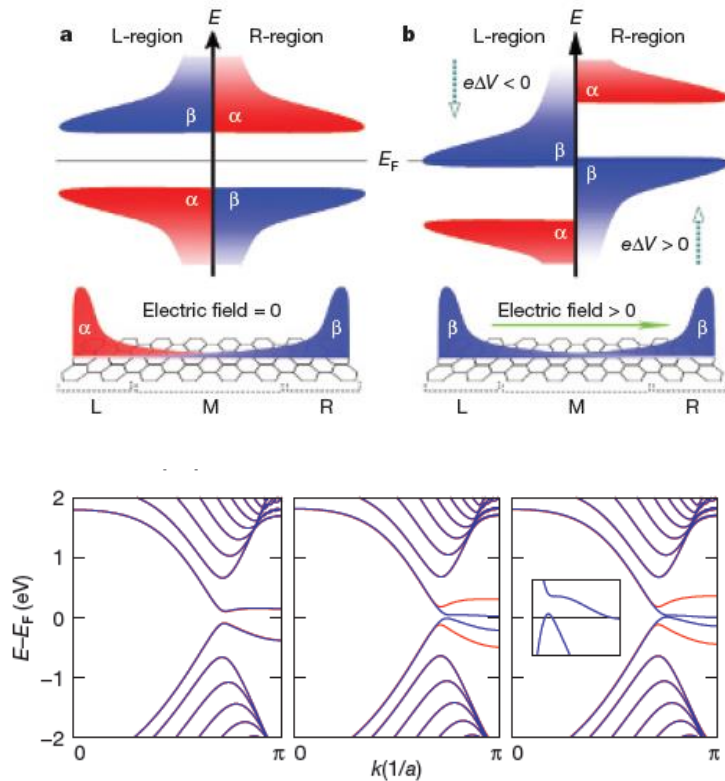


Huertas-Hernando et al., PRB **74** (2006)

Origin of spin polarization II

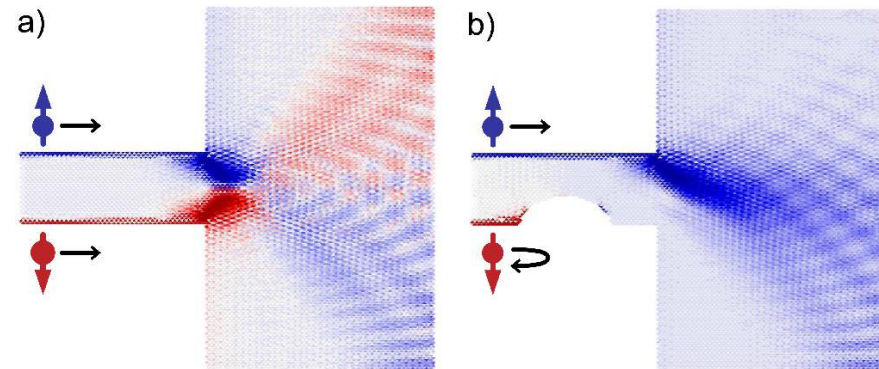
Spin polarized edge states

Half-metallicity



Son et al., Nature **444** (2006)

Edge roughness



Wimmer et al., PRL **100** (2008)

Relevant aspects addressed in TAILSPIN

I) Nanostructuring & functionalization

SiC-mesa via e-beam and optical lithography

II) Structure

STM and LEEM, edge orientation, curvature effects, relevant defects, adsorption sites, growth kinetics,...

III) Electronic structure & excitations

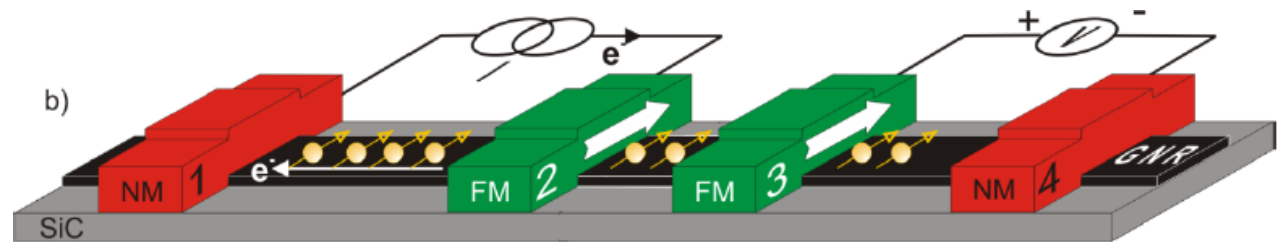
edge states, spin-resolved STS and ARPES to probe spin states, tuning by adsorption and intercalation RIXS,...

IV) Electronic transport

fundamental studies, impact of functionalization

V) Nanodevices

spin transport devices



→ close collaboration of partners from surface science and low temperature physics

→ bridge the gap between atomic and mesoscopic scales

TAILSPIN team

❑ Kees Flipse, University of Eindhoven
*low temperature **spin-STM** (high magnetic fields)*



❑ Ulrich Starke, MPI Stuttgart
*angle resolved photoemission (**spin-ARPES**)*



❑ Alexei Zakharov, Max lab Lund
*low energy electron microscopy (**LEEM**)*



❑ Bart van Wees, University of Groningen
*low temperature, **spin resolved transport** & devices*



❑ Christoph Tegenkamp, University of Hannover
*surface transport (**4-tip STM/SEM**), growth*



Work packages (WP) for TAILSPIN

	Topics	Partner	1-6	7-12	13-18	19-24	25-30	31-36
WP1	Fabrication of sidewall GNRs	1,4						
	Improvement: kinetics, edge states	2,3						
WP2	Functionalization: adsorption, defects, intercalation	2,4						
WP3	Local spin polarization: spin-STs	2						
	Band structure: PEEM, ARPES, spin-ARPES	1,3,4						
	Excitations: RIXS	2**						
WP4	Nanoscopic transport	1						
	Spin polarized and magneto transport	2***,5						
WP5	2-terminal (gated) nanodevices on pristine GNRs, four terminal devices	5						
	Fully GNR based two-terminal spin valve devices	5						

Partners:

1: Tegenkamp, Hannover
(4-tip STM/SEM)

2: Flipse, Eindhoven
(STM/STS)

3: Zakharov, Lund
(LEEM/PEEM)

4: Starke, Stuttgart
(ARPES)

5: van Wees, Groningen
(cryogenic transport)

** : RIXS in collaboration with
Jean-Pascual Rueff, SOLEIL

***: magneto Hall in coll. with
Ulrich Zeitler, Nijmegen

Complementarity and synergies with the Flagship CP

WP1 – Materials

- expertise in growth of graphene on SiC (Seyller, Yamikova, etc.)
- growth of nanostructures not in scope of WP1

WP3 – Fundamentals

- theoretical studies on defects, edges, interfaces, intercalates, ...

WP6 – Spintronic

- focusses „only“ on 2D graphene
- our nanostructures will complement the 2D efforts